# 2SJ399

## Silicon P-Channel MOS FET

# **HITACHI**

ADE-208-267 1st. Edition

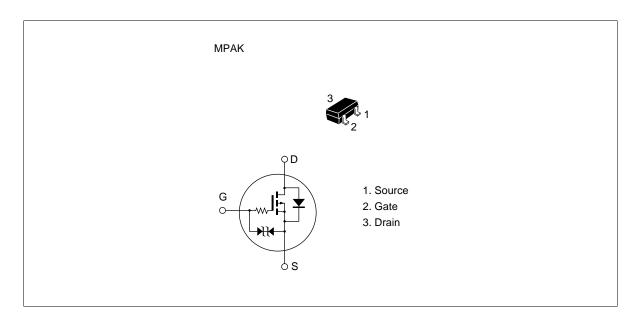
### **Application**

Low frequency power switching

#### **Features**

- Low on-resistance
- Small package
- Low drive current
- 4 V gate drive device can be driven from 5 V source
- Suitable for low signal load switch.

#### **Outline**





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## **Absolute Maximum Ratings** ( $Ta = 25^{\circ}C$ )

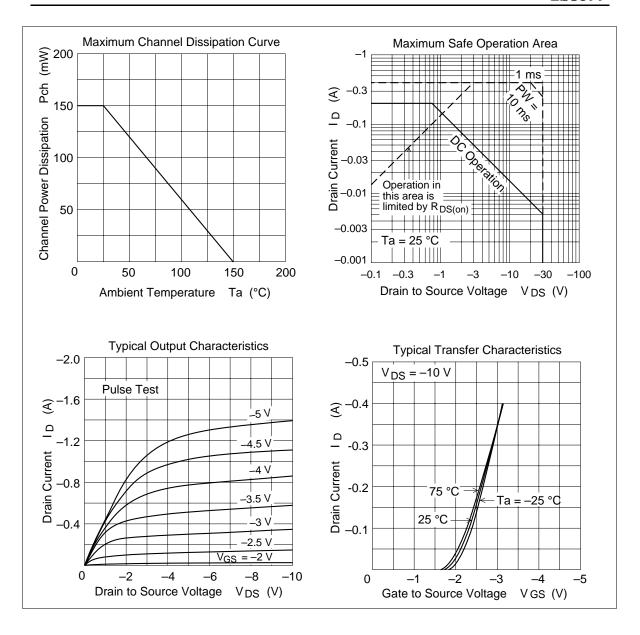
Item	Symbol	Ratings	Unit
Drain to source voltage	$V_{\scriptscriptstyle DSS}$	-30	V
Gate to source voltage	V <sub>GSS</sub>	±20	V
Drain current	I <sub>D</sub>	-0.2	А
Drain peak current	l <sub>D(pulse)</sub> *1	-0.4	А
Body to drain diode reverse drain current	I <sub>DR</sub>	-0.2	А
Channel dissipation	Pch	150	mW
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW  $\leq$  100  $\mu$ s, duty cycle  $\leq$  10%

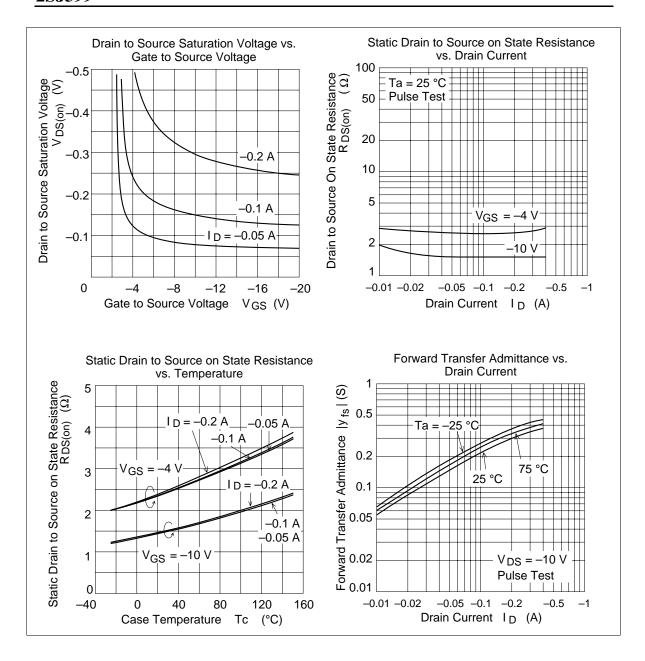
2. Marking is "ZF-"

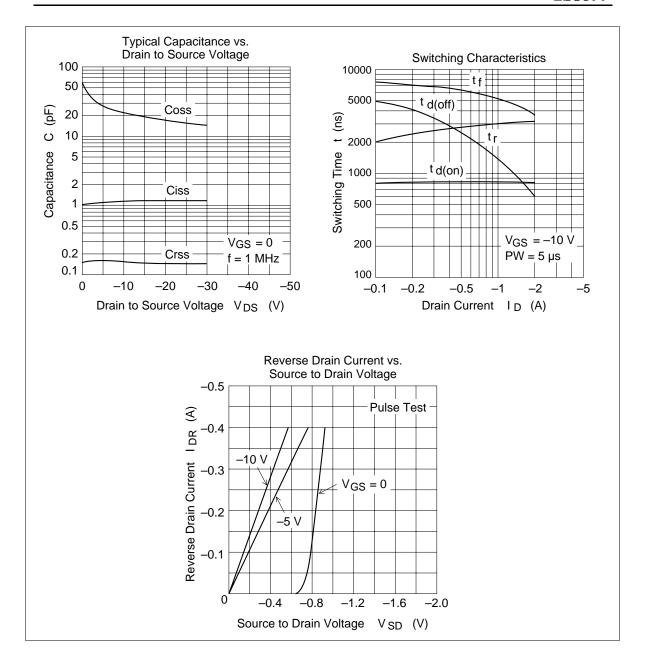
## **Electrical Characteristics** ( $Ta = 25^{\circ}C$ )

Item	Symbol	Min	Тур	Max	Unit	Test conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	-30	_	_	V	$I_D = -100 \ \mu A, \ V_{GS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	±20	_	_	V	$I_{G} = \pm 100 \ \mu A, \ V_{DS} = 0$
Gate to source leak current	I <sub>GSS</sub>	_	_	±2	μΑ	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I <sub>DSS</sub>	_	_	<b>–</b> 1	μΑ	$V_{DS} = -30 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	-1.0		-2.0	V	$I_D = -10 \mu A, V_{DS} = -5 V$
Static drain to source on state resistance	$R_{DS(on)}$	_	2.7	5.0	Ω	$I_D = -20 \text{ mA}$ $V_{GS} = -4 \text{ V}^{*1}$
		_	2.0	3.0	Ω	$I_D = -10 \text{ mA}$ $V_{GS} = -10 \text{ V}^{*1}$
Input capacitance	Ciss	_	1.1	_	pF	V <sub>DS</sub> = -10 V
Output capacitance	Coss	_	22.3	_	pF	$V_{GS} = 0$
Reverse transfer capacitance	Crss	_	0.17	_	pF	f = 1 MHz
Turn-on delay time	$t_{\text{d(on)}}$	_	530	_	ns	$I_D = -0.1 \text{ A}$
Rise time	t <sub>r</sub>	_	2170	_	ns	$V_{GS} = -10 \text{ V}$
Turn-off delay time	$t_{\text{d(off)}}$	_	7640	_	ns	$R_L = 100 \Omega$
Fall time	t <sub>f</sub>	_	7690	_	ns	PW = 5 μs

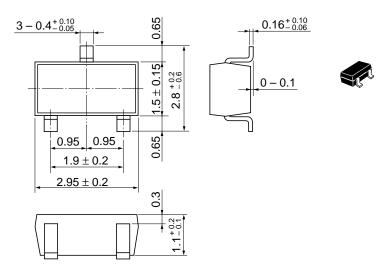


### 2SJ399





Unit: mm



Hitachi Code	MPAK
JEDEC	_
EIAJ	Conforms
Weight (reference value)	0.011 a

#### **Cautions**

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